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APPLICATION NO.	FIL	ING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/752,929	0	1/07/2004	Andrew Marshall	TI-20142.2	5790	
23494	7590	10/13/2005		EXAMINER		
TEXAS INS	TRUME	NTS INCORPOR	LE, THAO X			
P O BOX 655	5474, M/S	3999				
DALLAS, TX 75265				ART UNIT	PAPER NUMBER	
•	•			2814		

DATE MAILED: 10/13/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Applicat	on No.	Applicant(s)	(KN)			
	10/752,9	29	MARSHALL ET AL.				
Office Action Summary	Examine	r	Art Unit				
· ·	Thao X. I		2814				
The MAILING DATE of this commun Period for Reply	nication appears on th	e cover sheet with the c	orrespondence addres	ss			
A SHORTENED STATUTORY PERIOD IN THE MAILING DATE OF THIS COMMUN.  - Extensions of time may be available under the provision after SIX (6) MONTHS from the mailing date of this come. If the period for reply specified above is less than thirty (1) If NO period for reply is specified above, the maximum service is reply within the set or extended period for reply any reply received by the Office later than three months earned patent term adjustment. See 37 CFR 1.704(b).	IICATION. s of 37 CFR 1.136(a). In no e- munication. 30) days, a reply within the sta- statutory period will apply and v y will, by statute, cause the ap-	vent, however, may a reply be tim tutory minimum of thirty (30) day vill expire SIX (6) MONTHS from plication to become ABANDONE	nely filed s will be considered timely. the mailing date of this commu D (35 U.S.C. § 133).	inication.			
Status							
1)⊠ Responsive to communication(s) fil	ed on <u>13 May 2005</u> .						
	2b) This action is	non-final.					
	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims							
4) ☐ Claim(s) 25-28 is/are pending in the 4a) Of the above claim(s) is/s 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 25-28 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restr	are withdrawn from co						
Application Papers							
9) The specification is objected to by the specification is objected to by the specific to the	e: a) accepted or be ection to the drawing(s) ag the correction is requi	be held in abeyance. Sec red if the drawing(s) is ob	e 37 CFR 1.85(a). jected to. See 37 CFR 1				
Priority under 35 U.S.C. § 119							
a) All b) Some * c) None of:  1. Certified copies of the priority 2. Certified copies of the priority 3. Copies of the certified copies application from the Internation*  * See the attached detailed Office actions.	y documents have be y documents have be s of the priority docum onal Bureau (PCT Ru	en received. en received in Applicati ents have been receive lle 17.2(a)).	on No ed in this National Sta	ge			
Attachment(s)  1) Notice of References Cited (PTO-892)  2) Notice of Draftsperson's Patent Drawing Review (3) Information Disclosure Statement(s) (PTO-1449 of Paper No(s)/Mail Date		4) Interview Summary Paper No(s)/Mail D 5) Notice of Informal F 6) Other:		2)			

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### **DETAILED ACTION**

### Response to Amendment

1. Applicant's request for reconsideration of the finality of the rejection of the last
Office action is persuasive and, therefore, the finality of the Office action dated 07/21/05
is withdrawn. However, the following final Office action is based on the Applicant's
amendment dated 13 May 2005.

# Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 2. Claims 25-27 are rejected under 35 U.S.C. 102(e) as being anticipated by US 5596524 to Lin et al.

Regarding claim 25, Lin discloses a method for forming EEPROM cell in fig. 4B on a substrate, column 4 line 45, having an outer surface, the method comprising the steps of: forming a deep conductive region 408 of a first conductivity type (N-type), column 4 line 56, in the substrate below the substrate's outer surface; forming first and second conductive regions 402/403 of a first conductivity type (N), fig. 4B, in the

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substrate below the substrate's outer surface, the first and second conductive regions 402/403 are laterally displaced from one another by a predetermined distance, forming an insulating layer 404, column 4 line 51, outwardly from the outer surface of the substrate, fig. 4B, the insulating layer 404 positioned so that its edges are substantially in alignment between the first and second conductive regions 402/403, fig. 4B, forming a floating gate layer 406, column 4 line 50, outwardly from the insulating layer 404 and in substantially the same shape as the insulating layer 404, fig. 4B; and wherein the deep conductive region 220 is operable to provide a source of charge for placement on the floating gate layer 408 when programming the EEPROM cell, column 4 lines 57.

Regarding claims 26-27, Lin discloses the method wherein the insulating layer 404 is formed from oxide, column 4 line 47, wherein the floating gate layer 406 is formed from polysilicon, fig. 4A...

## Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation

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under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

5. Claim 28 is rejected under 35 U.S.C. 103(a) as being unpatentable over US 5596524 to Lin et al.

Regarding claim 28, Lin does not disclose the method wherein the deep conductive region 408 is doped on the order of 1x10<sup>16</sup> cm<sup>-3</sup>.

However, Lin discloses the method wherein the deep conductive region 408 is N+ doped, fig. 4B. Accordingly, it would have been obvious to one of ordinary skill in art to use the general concentration deep doping region 408 teaching of Lin in the range as claimed, because it has been held that where the general conditions of the claims are discloses in the prior art, it is not inventive to discover the optimum or workable range by routine experimentation. See In re Aller, 220 F.2d 454, 105 USPQ 233, 235 (CCPA 1955).

### Response to Arguments

6. Applicant's arguments with respect to claims 25-28 on 26 Sept 2005 have been considered but are most in view of the new ground(s) of rejection.

### Conclusion

7. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

8. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thao X. Le whose telephone number is (571) 272-1708. The examiner can normally be reached on M-F from 8:00 AM - 4:30 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael M. Fahmy can be reached on (571) 272 -1705. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Thao X. Le 03 Oct. 2005

LONG PHAM
PRIMARY EXAMINER